74CB3Q3253Dual 1-of-4 FET multiplexer/demultiplexer with charge pumpRev. 1 — 14 August 2017Product data sheet

1 General description

The 74CB3Q3253 is a dual high-bandwidth single-pole, quad-throw FET bus switch. Each switch features a select input (Sn) and an output enable input (\overline{nOE}). The switch is disabled when the \overline{nOE} input is HIGH. An internal charge-pump increases the gate voltage of the NMOS pass transistor. The result is improved R_{ON} and R_{ON(flat)} performance and the ability to switch 5 V signals when V_{CC} = 3.3 V.

2 Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- Overvoltage switching on switch ports:
 - 0 V to 5 V switching with V_{CC} = 2.5 V
 - 0 V to 5 V switching with V_{CC} = 3.3 V
- Switch voltage accepts signals up to 5.5 V
- 4 Ω (typical) ON resistance
- 3.5 pF (typical) OFF-state capacitance
- High bandwidth 0.5 GHz (maximum)
- · Low input/output capacitance minimizes loading and signal distortion
- Fast switching frequency f_{max} = 20 MHz (maximum)
- Low power consumption I_{CC} = 0.4 mA (typical)
- Control inputs can be driven by TTL or 5 V/3.3 V CMOS outputs
- I_{OFF} supports partial power-down mode operation
- · Latch-up performance exceeds 100 mA per JESD 78E Class II Level A
- ESD protection:
 - HBM ANSI/ESDA/JEDEC JS-001-2012 Class 2 exceeds 2 kV
 - CDM JESD22-C101F exceeds 1000 V
- Specified from -40 °C to +85 °C

3 Applications

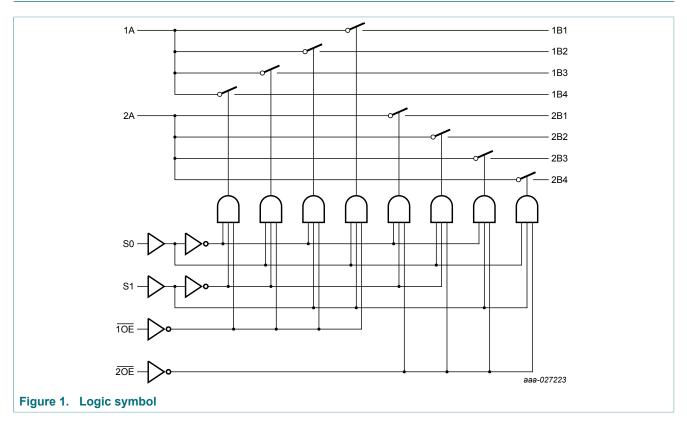
- Communication infrastructure
- Bus isolation
- Memory interleaving
- Sensor multiplexing

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4 Ordering information

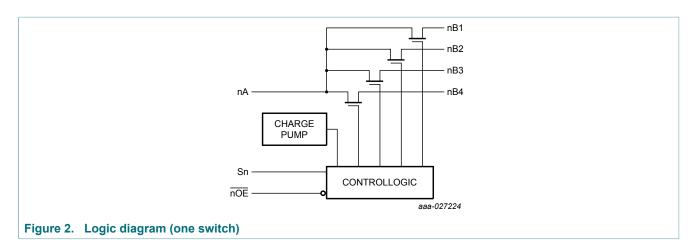
Table 1. Ordering	Information			
Type number	Package			
	Temperature range	Name	Description	Version
74CB3Q3253PW	-40 °C to +85 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74CB3Q3253BQ	-40 °C to +85 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm	SOT763-1

5 Functional diagram

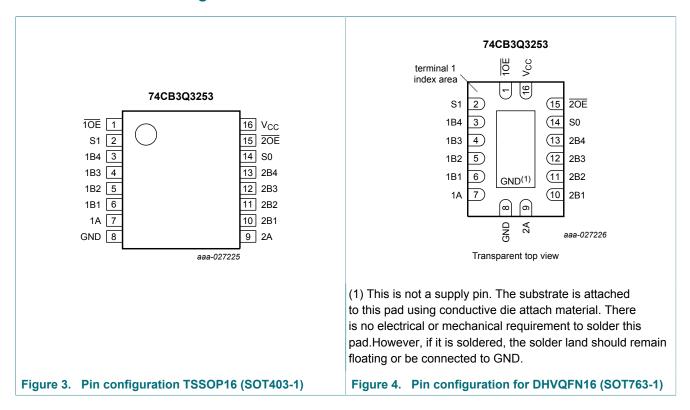


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6 **Pinning information**



6.1 Pinning

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6.2 Pin description

Table 2. Pin description		
Symbol	Pin	Description
10E	1	output enable input (active-LOW)
S1	2	select input
1B4	3	independent input or output
1B3	4	independent input or output
1B2	5	independent input or output
1B1	6	independent input or output
1A	7	common output or input
GND	8	ground (0 V)
2A	9	common output or input
2B1	10	independent input or output
2B2	11	independent input or output
2B3	12	independent input or output
2B4	13	independent input or output
S0	14	select input
20E	15	output enable input (active-LOW)
V _{CC}	16	supply voltage

7 Functional description

Table 3. Function table

H = *HIGH* voltage level; *L* = *LOW* voltage level; *X* = don't care; *Z* = high-impedance OFF-state.

Input			Channel on
S1	S0	nOE	
L	L	L	nA = nB1
L	Н	L	nA = nB2
Н	L	L	nA = nB3
Н	Н	L	nA = nB4
Х	X	Н	Z (switch off)

8 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	Sn, nOE input [1]	-0.5	+7.0	V
V _{SW}	switch voltage	[2]	-0.5	+7.0	V
I _{IK}	input clamping current	V _I < -0.5 V	-50	-	mA
I _{SK}	switch clamping current	V _I < -0.5 V	-50	-	mA
I _{SW}	switch current		-	±120	mA
I _{CC}	supply current		-	+100	mA
I _{GND}	ground current		-100	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +85 \text{ °C}$ [3]	-	500	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

[3] For TSSOP16 package: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

For DHVQFN16 package: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

9 Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage	Sn, nOE input	0	5.5	V
V _{SW}	switch voltage		0	5.5	V
T _{amb}	ambient temperature		-40	+85	°C
Δt/ΔV	input transition rise and fall rate	Sn, nOE input			
		V_{CC} = 2.3 V to 2.7 V	0	20	ns/V
		V _{CC} = 2.7 V to 3.6 V	0	10	ns/V

10 Static characteristics

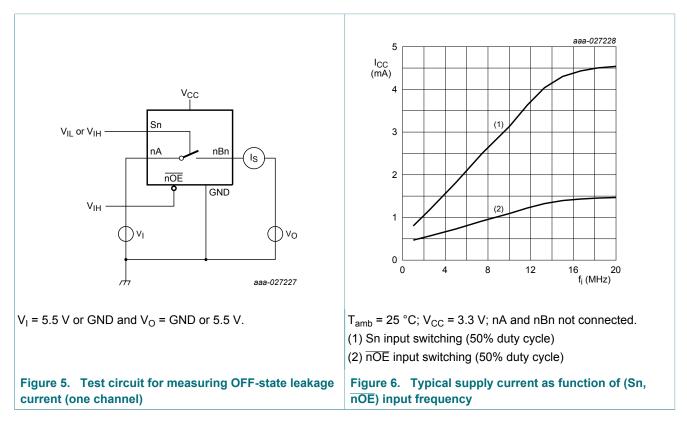
Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =-40 °	°C to +85 °C	Unit
			Min	Typ ^[1]	Max	Min	Max	
V _{IH}	HIGH-level	V_{CC} = 2.3 V to 2.7 V	-	-	-	1.7	-	V
	input voltage	V _{CC} = 2.7 V to 3.6 V	-	-	-	2	-	V
V _{IL}	LOW-level	V _{CC} = 2.3 V to 2.7 V	-	-	-	-	0.7	V
	input voltage	V _{CC} = 2.7 V to 3.6 V	-	-	-	-	0.8	V
V _{IK}	input clamping voltage	nA; nBn; V _{CC} = 3.6 V; I _I = -18 mA	-	-	-	-	-1.8	V
l _l	input leakage current	Sn, nOE ; V _{CC} = 3.6 V; V _I = GND to 5.5 V	-	-	-	-	±1	μA
I _{OFF}	power-off leakage current	per pin; $V_{CC} = 0 V$; V_{SW} or $V_I = 0 V$ to 5.5 V	-	-	-	-	±1	μA
I _{S(OFF)}	OFF-state leakage current	nA; nBn; V _{CC} = 3.6 V; see <u>Figure 5</u>	-	-	-	-	±1	μA
I _{CC}	supply current	V_1 = GND or V_{CC} ; I_0 = 0 A; V_{SW} = GND or V_{CC} ; V_{CC} = 3.6 V	-	0.4	-	-	0.6	mA
ΔI _{CC}	additional supply current	Sn, $\overline{\text{NOE}}$; V _{CC} = 3.6 V; one input at 3 V, other inputs at GND or V _{CC}	-	-	-	-	30	μA
Cı	input capacitance	V _{CC} = 3.3 V; V _{SW} = GND or V _{CC} ; V _I = 0 V, 3.3 V, 5.5 V						
		Sn, nOE	-	2.5	-	-	3.5	pF
$C_{S(OFF)}$	OFF-state	V_{CC} = 3.3 V; V_{SW} = 0 V, 3.3 V, 5.5 V						
	capacitance	nA	-	8	-	-	11	pF
		nBn	-	3.5	-	-	4.5	pF
C _{S(ON)}	ON-state	V_{CC} = 3.3 V; V_{SW} = 0 V, 3.3 V, 5.5 V						
	capacitance	nA, nBn	-	13	-	-	17	pF

[1] Typical values are measured at V_{CC} = 3.3 V unless otherwise specified.

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10.1 Test circuit and graph

10.2 ON resistance

Table 7. ON resistance

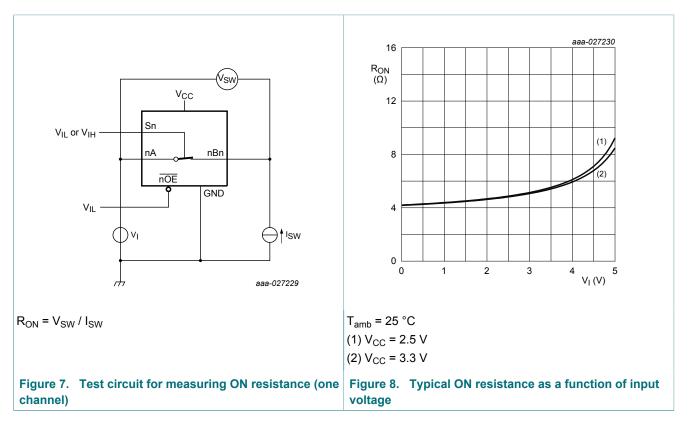
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

Symbol	Parameter	Conditions		Ta	amb = 25 °	°C	T _{amb} = -40 °	C to +85 °C	Unit
				Min	Тур	Мах	Min	Мах	
R _{ON}	ON resistance	V _{CC} = 2.3 V; see <u>Figure 8</u>							
		V _I = 0 V; I _{SW} = 30 mA	[1]	-	4	-	-	10	Ω
		V _I = 1.7 V; I _{SW} = -15 mA	[1]	-	4.5	-	-	11	Ω
		V _{CC} = 3.0 V; see <u>Figure 8</u>							
		V _I = 0 V; I _{SW} = 30 mA	[2]	-	4	-	-	8	Ω
		V _I = 2.4 V; I _{SW} = -15 mA	[2]	-	4.8	-	-	10	Ω

[1] Typical values are measured at V_{CC} = 2.5 V.

[2] Typical values are measured at V_{CC} = 3.3 V.

Dual 1-of-4 FET multiplexer/demultiplexer with charge pump



10.3 ON resistance test circuit and graph

11 Dynamic characteristics

Table 8. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 11.

Symbol	Parameter	Conditions	T _{amb} = -40 °	C to +85 °C	Unit
			Min	Мах	
t _{pd}	propagation	nA to nBn or nBn to nA; see Figure 9 [1] [2]			
	delay	V _{CC} = 2.3 V to 2.7 V	-	0.12	ns
		V _{CC} = 3.0 V to 3.6 V	-	0.2	ns
		Sn to nA; see Figure 9 [1]			
		V _{CC} = 2.3 V to 2.7 V	1.5	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	5.9	ns
t _{en}	enable time	nOE to nA, nBn; see Figure 10 [1]			
		V _{CC} = 2.3 V to 2.7 V	1.5	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	5.9	ns
		Sn to nBn; see <u>Figure 10</u> [1]			
		V _{CC} = 2.3 V to 2.7 V	1.5	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	5.9	ns

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Symbol	Parameter	Conditions		T _{amb} = -40 °	C to +85 °C	Unit
				Min	Max	
t _{dis}	disable time	nOE to nA, nBn; see Figure 10	[1]			
		V _{CC} = 2.3 V to 2.7 V		1.0	6.1	ns
		V _{CC} = 3.0 V to 3.6 V		1.0	6.1	ns
		Sn to nBn; see Figure 10	[1]			
		V _{CC} = 2.3 V to 2.7 V		1.0	6.1	ns
		V _{CC} = 3.0 V to 3.6 V		1.0	6.1	ns
f _{max}	maximum	Sn, $\overline{\text{nOE}}$; V _O > V _{CC} ; V _I = 5 V; R _L ≥ 1 MΩ; C _L = 0 pF				
	frequency	V_{CC} = 2.3 V to 2.7 V		-	10	MHz
		V _{CC} = 3.0 V to 3.6 V		-	20	MHz

[1] t_{pd} is the same as t_{PLH} and $t_{\text{PHL}}.$ t_{en} is the same as t_{PZL} and $t_{\text{PZH}}.$

 t_{dis} is the same as t_{PLZ} and t_{PHZ} . The propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified load capacitance, when driven by an [2] ideal voltage source (zero output impedance).

11.1 Waveforms and test circuit

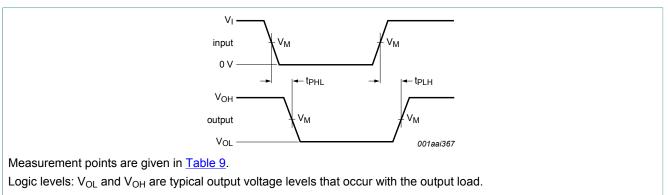
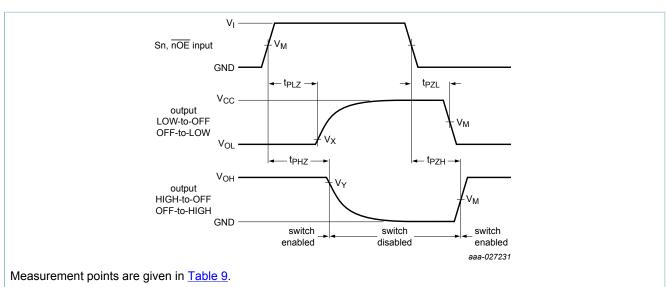


Figure 9. The data input (nA or nBn) to output (nBn or nA) propagation delays

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Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 10. Enable and disable times

Table 9. Measurement points

Supply voltage	Input	Output		
V _{CC}	V _M	V _M	V _X	V _Y
2.3 V to 2.7 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V
3.0 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V

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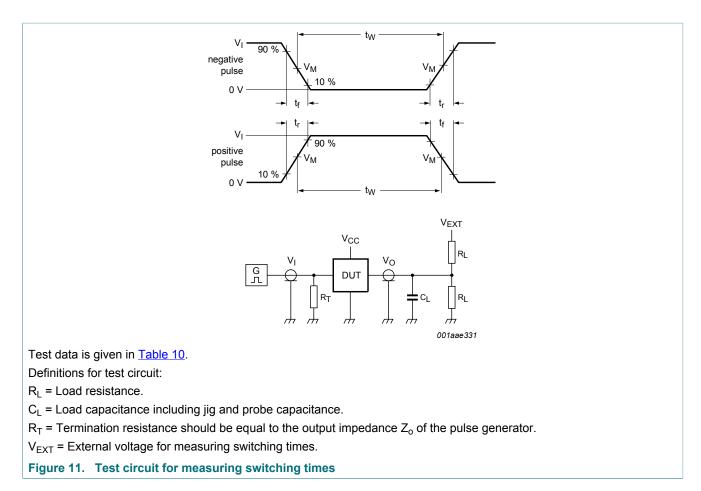


Table 10. Test data

Supply voltage	Input		Load		V _{EXT}			
V _{cc}	VI	t _r , t _f	CL	R _L	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PZH} , t _{PHZ}	
2.3 V to 2.7 V	V _{CC}	≤ 2.5 ns	30 pF	500 Ω	open	$2 \times V_{CC}$	GND	
3.0 V to 3.6 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	2 × V _{CC}	GND	

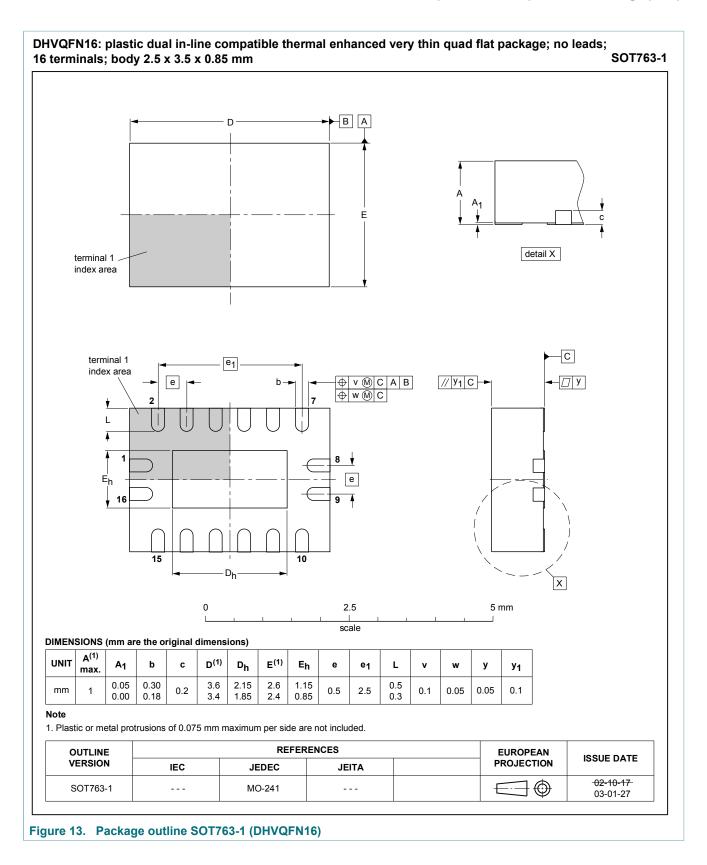
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12 Package outline

	6: pla	stic th	1in sh	rink s	mall	outlin	e pacl	kage;	16 lea	ads; b	ody v	vidth 4	l.4 m	m			S	OT403
		Ē			- D				c			— E -				X	A	
				z pin 1 e			9 	w (M)			<u>↓</u>		L- etail X		(A ₃) ↓ ↓ ↓ ↓	Α Ψ θ		
				jinal dim			0		2.5 scale		5 mm						(1)	
UNIT	A max.	nm are 1 A ₁ 0.15	A ₂	A ₃	b _p	s) c 0.2	0 D (1) 5.1	E ⁽²⁾ 4.5	scale e	Н _Е 6.6	L	L р 0.75	Q 0.4	v	w	у	Z ⁽¹⁾ 0.40	θ 8°
UNIT mm Notes	A max. 1.1	A ₁ 0.15 0.05	A ₂ 0.95 0.80	A ₃ 0.25	b p 0.30 0.19 m maxin	c 0.2 0.1	D (1) 5.1 4.9 side are	4.5 4.3 e not inc	e 0.65	Н Е 6.6 6.2		L _p 0.75 0.50	Q 0.4 0.3	v 0.2	w 0.13	y 0.1	Z (1) 0.40 0.06	
UNIT mm lotes . Plastic . Plastic	A max. 1.1 c or meta c interlea	A ₁ 0.15 0.05	A ₂ 0.95 0.80	A ₃ 0.25	b p 0.30 0.19 m maxin	c 0.2 0.1	D (1) 5.1 4.9 side are	4.5 4.3 e not inc	e 0.65	6.6	L	0.75	0.4	0.2	0.13	0.1	0.40 0.06	8° 0°
UNIT mm lotes . Plastic . Plastic OL VE	A max. 1.1	A1 0.15 0.05	A ₂ 0.95 0.80 sions of	A ₃ 0.25	b p 0.30 0.19 m maxin	c 0.2 0.1	D (1) 5.1 4.9 side are r side ar REFEF	4.5 4.3 e not inc e not inc	e 0.65	6.6	L	0.75	0.4	0.2	0.13	0.1	0.40	8° 0°

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13 Abbreviations

Table 11. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal Oxide Semiconductor			
ESD	ElectroStatic Discharge			
НВМ	Human Body Model			

14 Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74CB3Q3253 v.1	20170814	Product data sheet	-	-

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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